

INFORMATION DISCLOSURE STATEMENT

Applicant : Sherman
App. No : 10/683,727
Filed : October 10, 2003
For : SEQUENTIAL CHEMICAL VAPOR
DEPOSITION
Examiner : Kelly M. Stouffer
Art Unit : 1762

CERTIFICATE OF EFS WEB
TRANSMISSION

I hereby certify that this correspondence, and any other attachment noted on the automated Acknowledgement Receipt, is being transmitted from within the Pacific Standard Time (PST) zone to the Commissioner for Patents via the EFS Web server on:

June 22, 2007

(Date)

Zi Y. Wong, Reg. No. 58,410

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Enclosed for filing in the above-identified application is a PTO/SB/08 Equivalent listing 3 references to be considered by the Examiner. Also enclosed are 3 foreign patent references and/or non-patent literature as listed on the Information Disclosure Statement.

This Information Disclosure Statement is being filed within three months of the filing date, with an RCE or before receipt of a first office action after an RCE and no fee is required.

The Commissioner is hereby authorized to charge any additional fees which may be required or to credit any overpayment to Account No. 11-1410.

Respectfully submitted,

KNOBBE, MARTENS, OLSON & BEAR, LLP

Dated: 6/22/07

By: Zi Y. Wong
Registration No. 58,410
Attorney of Record
Customer No. 20,995
(415) 954-4114

INFORMATION DISCLOSURE STATEMENT BY APPLICANT	Application No.	10/683,727
	Filing Date	October 10, 2003
	First Named Inventor	Sherman
	Art Unit	1762
(Multiple sheets used when necessary)	Examiner	Kelly M. Stouffer
SHEET 1 OF 1	Attorney Docket No.	ASMMC.9CP1DV1C1

U.S. PATENT DOCUMENTS

Examiner Initials	Cite No.	Document Number Number - Kind Code (if known) Example: 1,234,567 B1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear
----------------------	-------------	---	--------------------------------	-------------------------------	--

FOREIGN PATENT DOCUMENTS

Examiner Initials	Cite No.	Foreign Patent Document Country Code-Number-Kind Code Example: JP 1234567 A1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear	T ¹
----------------------	-------------	--	-----------------------------------	----------------------------------	--	----------------

NON PATENT LITERATURE DOCUMENTS

Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ¹
		20a-ZC-1, MIYAMOTO et al., "High-Fluidity Deposition of SiN by Cryogenic Remote Plasma CVD," Research Center for Integrated Systems and Faculty of Engineering, Hiroshima University, 1 page.	✓
		20a-ZC-2, GOTOU et al., "Atomic-Layer Deposition of SiN by Remote Plasma CVD," Research Center for Integrated Systems, Hiroshima University, 2 pages.	✓
		20a-ZC-3, NAKAMURA et al., "Atomic-Layer Deposition of SiO ₂ by Remote Plasma CVD," Research Center for Integrated Systems, Hiroshima University, 1 page.	✓

3917458
062207

Examiner Signature	Date Considered
--------------------	-----------------

*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

T¹ - Place a check mark in this area when an English language Translation is attached.